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## HMC7229LS6



## GaAs pHEMT MMIC 1 WATT POWER AMPLIFIER With Power Detector, 37 - 40 GHz

#### **Typical Applications**

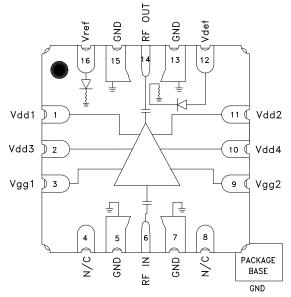
The HMC7229LS6 is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- VSAT & SATCOM

#### Features

+32 dBm Pout @ 18% PAE P1dB Output Power: +31.5 dBm High Output IP3: +40 dBm High Gain: 24 dB 50 Ohm Matched Input/Output Ceramic 6x6 mm High Frequency Air Cavity Package

#### Functional Diagram



#### **General Description**

The HMC7229LS6 is a four-stage GaAs pHEMT MMIC 1 Watt Power Amplifier, with an integrated temperature compensated on-chip Power Detector, which operates between 37 and 40 GHz. The HMC7229LS6 provides 24 dB of gain, and +32 dBm of saturated output power at 18% PAE from a +6V supply. With an excellent IP3 of +40 dBm, the HMC7229LS6 is ideal for linear applications such as high capacity point-to-point or multi-point radios or VSAT/SATCOM applications demanding +32 dBm of efficient saturated output power. The RF I/Os are internally matched and DC blocked for ease of integration into higher level assemblies. The HMC7229LS6 is housed in a ceramic 6x6 mm high frequency air cavity package which exhibits low thermal resistance and is compatible with surface mount manufacturing techniques

#### **Electrical Specifications** $T_A = +25^{\circ}$ C, Vdd = Vdd1 = Vdd2 = Vdd3 = Vdd4 = +6V, Idd = 1200 mA

Parameter	Min.	Тур.	Max.	Units
Frequency Range		37 - 40		GHz
Gain	21	24		dB
Gain Variation over Temperature		0.058		dB/°C
Input Return Loss		16		dB
Output Return Loss		14		dB
Output Power for P1dB Compression	28.5	31.5		dBm
Saturated Output Power (Psat)		32		dBm
Output Third Order Intercept (IP3) <sup>[2]</sup>		40		dBm
Total Supply Current (Idd)		1200		mA

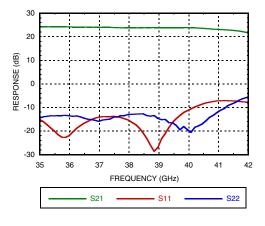
[1] Adjust Vgg between -2 to 0V to achieve Idd = 1200mA typical

[2] Measurement taken at Pout / tone = +20dBm.

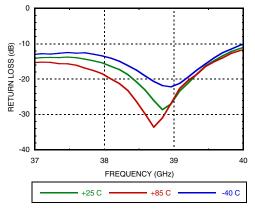




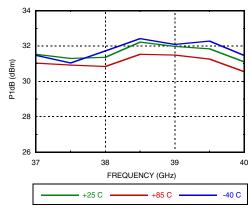
#### Gain & Return Loss



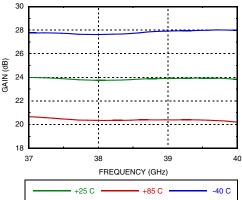
#### Input Return Loss vs. Temperature



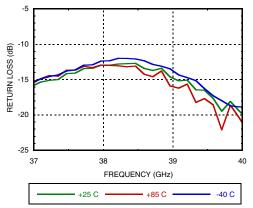
#### P1dB vs. Temperature



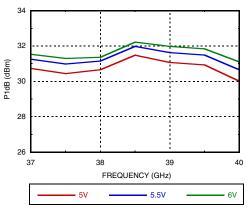
#### Gain vs. Temperature



#### **Output Return Loss vs. Temperature**



P1dB vs. Supply Voltage

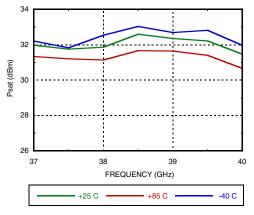




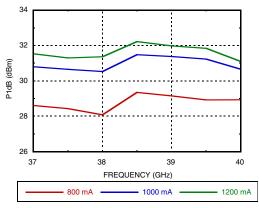




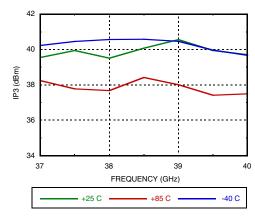
#### Psat vs. Temperature

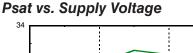


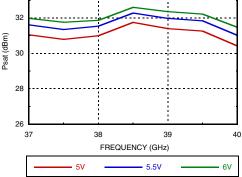
P1dB vs. Supply Current



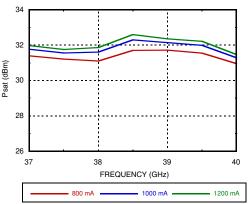
Output IP3 vs. Temperature, Pout/tone = +20 dBm



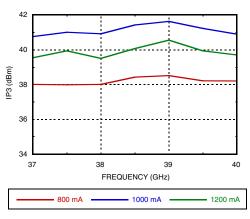




Psat vs. Supply Current



Output IP3 vs. Supply Current, Pout/tone = +20 dBm



For price, delivery and to place orders: Hittite Microwave Corporation, 2 Elizabeth Drive, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com

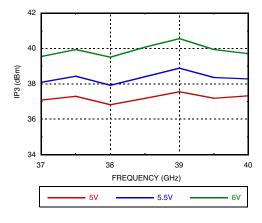


## HMC7229LS6

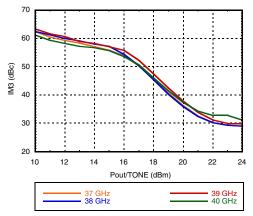


GaAs pHEMT MMIC 1 WATT POWER AMPLIFIER With Power Detector, 37 - 40 GHz

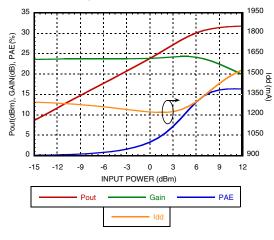
Output IP3 vs. Supply Voltage, Pout/tone = +20 dBm

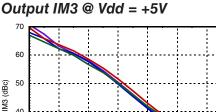


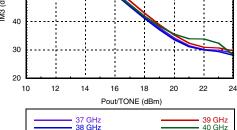
#### Output IM3 @ Vdd = +5.5V



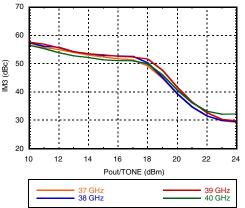
#### Power Compression @ 38 GHz



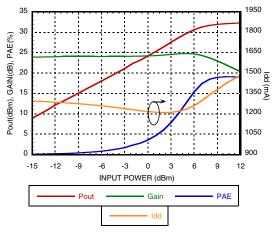




Output IM3 @ Vdd = +6V



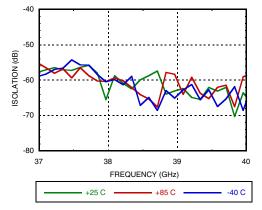
Power Compression @ 39 GHz



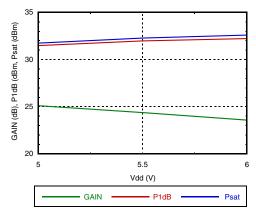


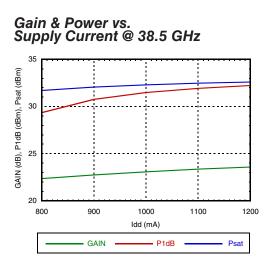


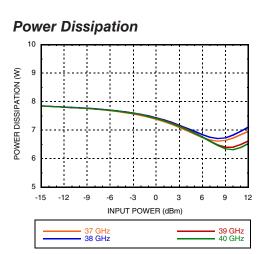
#### Reverse Isolation vs. Temperature

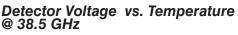


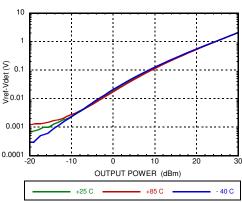
Gain & Power vs. Supply Voltage @ 38.5 GHz













#### Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+7V
RF Input Power (RFIN)	+21 dBm
Channel Temperature	175 °C
Continuous Pdiss (T= 85 °C) (derate 95 mW/°C above 85 °C)	9.0 W
Thermal Resistance (channel to ground paddle)	10 °C/W
Operating Temperature	-65°C to +150°C
Storage Temperature	-40°C to 85°C
ESD Sensitivity (HBM)	Class 0, Passed 150V

#### Typical Supply Current vs. Vdd

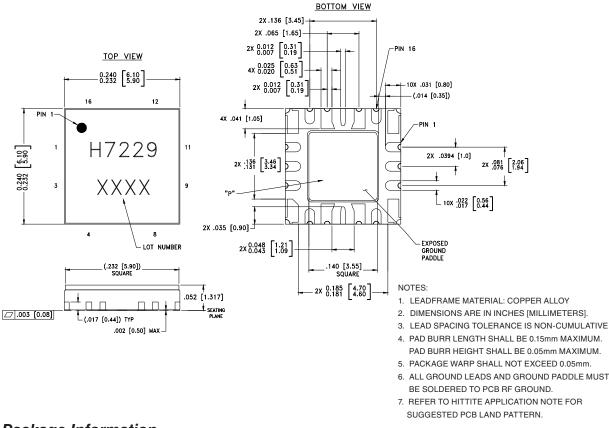
Vdd (V)	ldd (mA)
+5	1200
+5.5	1200
+6	1200

Adjust Vgg1 to achieve Idd = 1200 mA



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

#### **Outline Drawing**



#### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating <sup>[2]</sup>	Package Marking <sup>[1]</sup>
HMC7229LS6	ALUMINA WHITE	Gold over Nickel	N/A <sup>[3]</sup>	<u>H7229</u> XXXX

[1] 4-Digit lot number XXXX.

[2] Max peak reflow temperature of 260 °C.

[3] Not Applicable to air cavity packages.





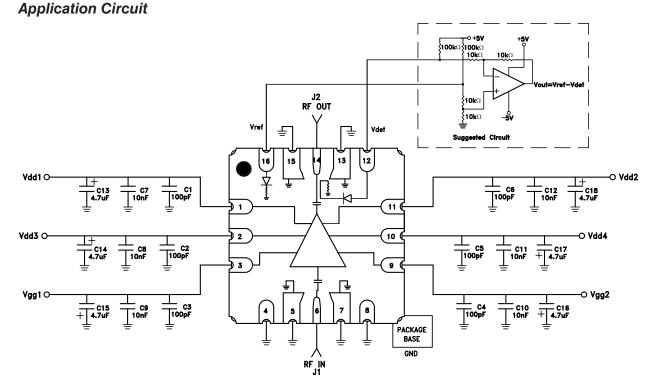
#### **Pin Descriptions**

Pin Number	Function	Description	Pin Schematic
1, 2, 10, 11	Vdd1, Vdd3, Vdd4, Vdd2	Drain bias voltage. External bypass capacitors of 100 pF, 10 nF and 4.7 μF are required for each pin.	0 Vdd1−4
3, 9	Vgg1, Vgg2	Gate control for PA. Adjust Vgg to achieve recommended bias current. External bypass caps 100 pF, 10 nF and 4.7 μF are required. Apply Vgg bias to either pin 3 or pin 9.	Vgg1-2
4, 8	N/C	These pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
5, 7, 13, 15	GND	These pins and the exposed ground paddle must be connected to RF/DC ground.	
6	RF IN	This pin is AC coupled and matched to 50 Ohms.	
16	Vref	DC voltage of diode biased through external resistor used for temperature compensation of Vdet. See appli- cation circuit.	OVref
12	Vdet	DC voltage representing RF output power rectified by diode which is biased through an external resistor. See application circuit.	OVdet
14	RF OUT	This pin is AC coupled and matched to 50 Ohms.	





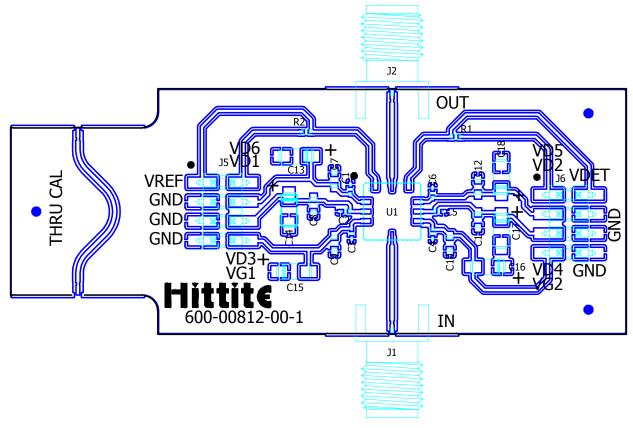








#### **Evaluation PCB**



#### List of Materials for Evaluation PCB EV1HMC7229LS6 [1]

Item	Description	
J1 - J2	"K" Connector, SRI	
J5 - J6	DC Pin	
C1 - C6	100 pF Capacitor, 0402 Pkg.	
C7 - C12	10000 pF Capacitor, 0603 Pkg	
C13 - C18	4.7 uF Capacitor, Case A Pkg.	
R1 - R2	40.2K Ohm Resistor, 0402 Pkg.	
U1	HMC7229LS6 Amplifier	
PCB [2]	600-00812-00 Evaluation Board	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

 List of Matel

 Item

 J1 - J2

 J5 - J6

 C1 - C6

 C7 - C12

 C13 - C18

 R1 - R2

 U1

 PCB [2]

 [1] Reference this number





Notes